





### 40V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

## **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> T <sub>C</sub> = +25°C
40V	1.8mΩ @ V <sub>GS</sub> = 10V	210A

# **Description and Applications**

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Engine Management Systems
- Body Control Electronics
- DC-DC Converters

### **Features**

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- Thermally Efficient Package-Cooler Running Applications
- High Conversion Efficiency
- Low RDS(ON) Minimizes On State Losses
- <1.1mm Package Profile Ideal for Thin Applications
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH41M8SPSQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

#### **Mechanical Data**

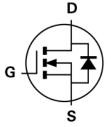
- Case: PowerDI<sup>®</sup>5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)



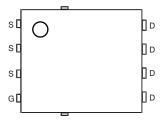




Bottom View







Top View Pin Configuration

# Ordering Information (Note 4)

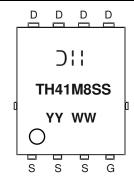
Top View

Part Number	Case	Packaging
DMTH41M8SPSQ-13	PowerDI5060-8 (Type K)	2,500 / Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

## **Marking Information**



J!! = Manufacturer's Marking
 TH41M8SS = Product Type Marking Code
 YYWW = Date Code Marking
 YY = Last Two Digits of Year (ex: 20 = 2020)
 WW = Week Code (01 to 53)



# **Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	VDSS	40	V	
Gate-Source Voltage	Vgss	±20	V	
Continuous Drain Current, V <sub>GS</sub> = 10V (Note 6)	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$	lo	210 150	Α
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	840	Α	
Continuous Body Diode Forward Current (Note 6) T <sub>C</sub> = +25°C		Is	210	Α
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)	Ism	840	Α	
Avalanche Current, L = 0.1mH	las	72.8	Α	
Avalanche Energy, L = 0.1mH	Eas	265	mJ	

### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	PD	3.06	W
Thermal Resistance, Junction to Ambient (Note 5)  Steady State		RθJA	49	°C/W
Total Power Dissipation (Note 6) $T_C = +25^{\circ}C$		PD	150	W
Thermal Resistance, Junction to Case (Note 6)	R <sub>θ</sub> JC	1.0	°C/W	
Operating and Storage Temperature Range	TJ, TSTG	-55 to +175	°C	

# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

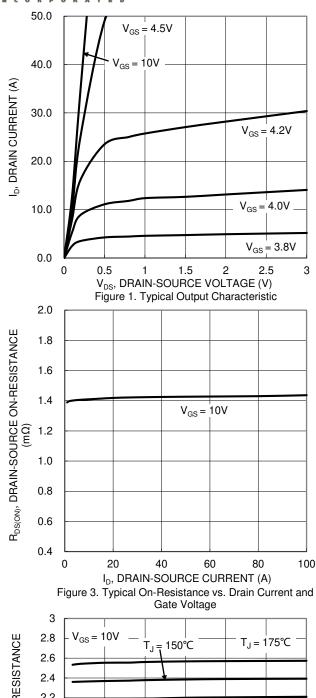
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	40	_	_	V	$V_{GS} = 0V, I_{D} = 250\mu A$	
Zero Gate Voltage Drain Current	IDSS	_	_	1	μA V <sub>DS</sub> = 32V, V <sub>GS</sub> = 0V		
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 20V$ , $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	2	1	4	V	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$	
Static Drain-Source On-Resistance	RDS(ON)	_	1.4	1.8	mΩ	$V_{GS} = 10V, I_{D} = 30A$	
Diode Forward Voltage	$V_{SD}$	_	0.8	1.2	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	6968		pF	V <sub>DS</sub> = 20V, V <sub>GS</sub> = 0V, f = 1MHz	
Output Capacitance	Coss	_	1812	1			
Reverse Transfer Capacitance	Crss	_	59	_			
Gate Resistance	Rg	_	1.21	1	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge	$Q_g$	_	79.5			V <sub>DD</sub> = 20V, I <sub>D</sub> = 90A, V <sub>GS</sub> = 10V	
Gate-Source Charge	Qgs	_	20.6	_	nC		
Gate-Drain Charge	$Q_{gd}$	_	16.5	_		VGS = 10V	
Turn-On Delay Time	td(ON)	_	13.3	_		$V_{DD} = 20V, V_{GS} = 10V,$ $I_{D} = 90A, R_{G} = 3.5\Omega$	
Turn-On Rise Time	t <sub>R</sub>	_	41.3	_			
Turn-Off Delay Time	tD(OFF)	_	35.1	_	ns		
Turn-Off Fall Time	tr	_	13.7	_			
Reverse Recovery Time	trr	_	62	_	ns	I <sub>F</sub> = 50A, di/dt = 100A/µs	
Reverse Recovery Charge	Qrr	_	103	_	nC	7 IF = 30A, αΙ/αι = 100A/μ5	

5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

<sup>6.</sup> Thermal resistance from junction to soldering point (on the exposed drain pad).

<sup>7.</sup> Short duration pulse test used to minimize self-heating effect. 8. Guaranteed by design. Not subject to product testing.





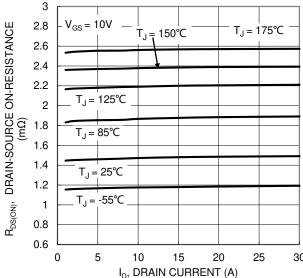
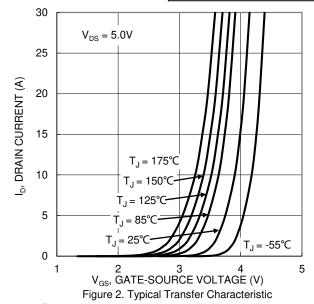
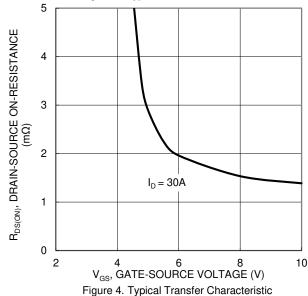


Figure 5. Typical On-Resistance vs. Drain Current and Temperature





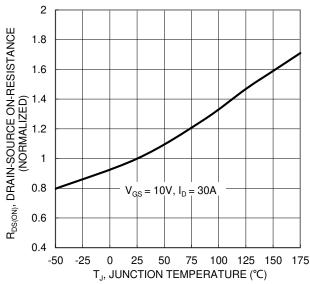


Figure 6. On-Resistance Variation with Temperature





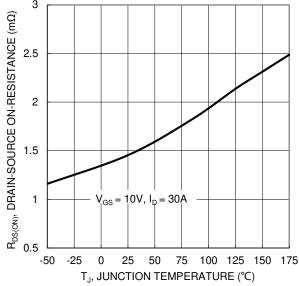


Figure 7. On-Resistance Variation with Temperature

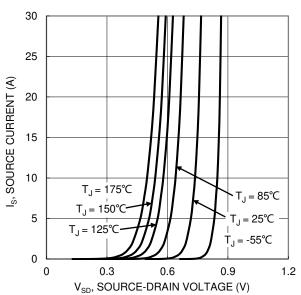


Figure 9. Diode Forward Voltage vs. Current 10 8 6  $V_{GS}(V)$  $V_{DS} = 20V, I_{D} = 90A$ 4 2 0 0 20 40 60 80  $Q_q$  (nC) Figure 11. Gate Charge

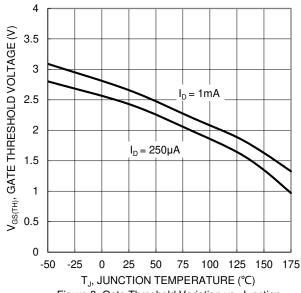
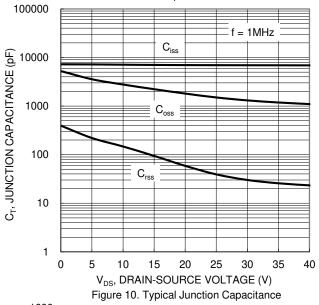


Figure 8. Gate Threshold Variation vs. Junction Temperature



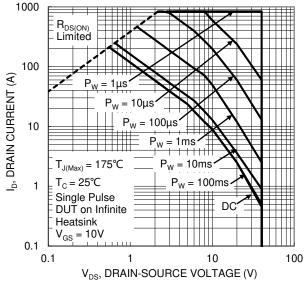
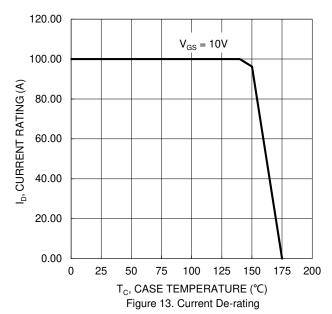


Figure 12. SOA, Safe Operation Area





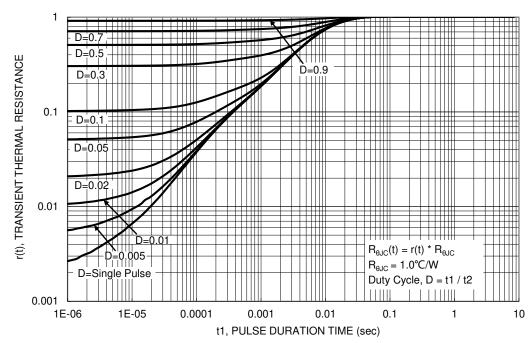


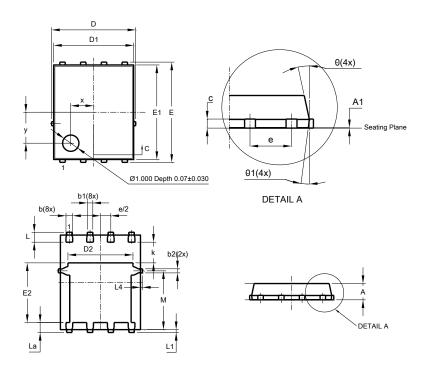
Figure 14. Transient Thermal Resistance



# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### PowerDI5060-8 (Type K)

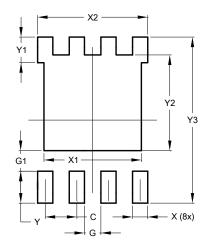


PowerDI5060-8					
(Type K)					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
<b>A</b> 1	0	0.05	0.02		
b	0.33	0.51	0.41		
b1	0.300	0.366	0.333		
b2	0.20	0.35	0.25		
C D	0.23	0.33	0.277		
_		.15 BS			
D1	4.85	4.95	4.90		
D2	-	-	3.98		
Е	6	.15 BS(	$\sim$		
E1	5.75	5.85	5.80		
E2	3.56	3.725	3.66		
е	1	.27BS0			
k	-	-	1.27		
L	0.51	0.71	0.61		
La	0.51	0.675	0.61		
L1	0.05	0.20	0.175		
L4	-	-	0.125		
М	3.50	3.71	3.605		
X	-	-	1.400		
у	-	-	1.900		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5060-8 (Type K)



Dimensions	Value (in mm)		
С	1.270		
G	0.660		
G1	0.820		
X	0.610		
X1	3.910		
X2	4.420		
Υ	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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